

NCV8450

Self-Protected High Side Driver with Temperature and Current Limit

The NCV8450 is a fully protected High-Side Smart Discrete device with a typical $R_{DS(on)}$ of $1.0\ \Omega$ and an internal current limit of $0.8\ A$ typical. The device can switch a wide variety of resistive, inductive, and capacitive loads.

Features

- Short Circuit Protection
- Thermal Shutdown with Automatic Restart
- Overvoltage Protection
- Integrated Clamp for Inductive Switching
- Loss of Ground Protection
- ESD Protection
- Slew Rate Control for Low EMI
- Very Low Standby Current
- AEC-Q100/101 qualified
- This is a Pb-Free Device

Typical Applications

- Automotive
- Industrial

PRODUCT SUMMARY

Symbol	Characteristics	Value	Unit
V_{IN_CL}	Overvoltage Protection	54	V
$V_{D(on)}$	Operation Voltage	4.5 – 45	V
R_{on}	On-State Resistance	1.0	Ω



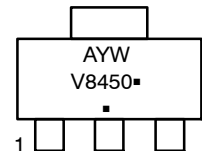
ON Semiconductor®

<http://onsemi.com>

MARKING DIAGRAM



SOT-223
(TO-261)
CASE 318E



A = Assembly Location
Y = Year
W = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

NCV8450

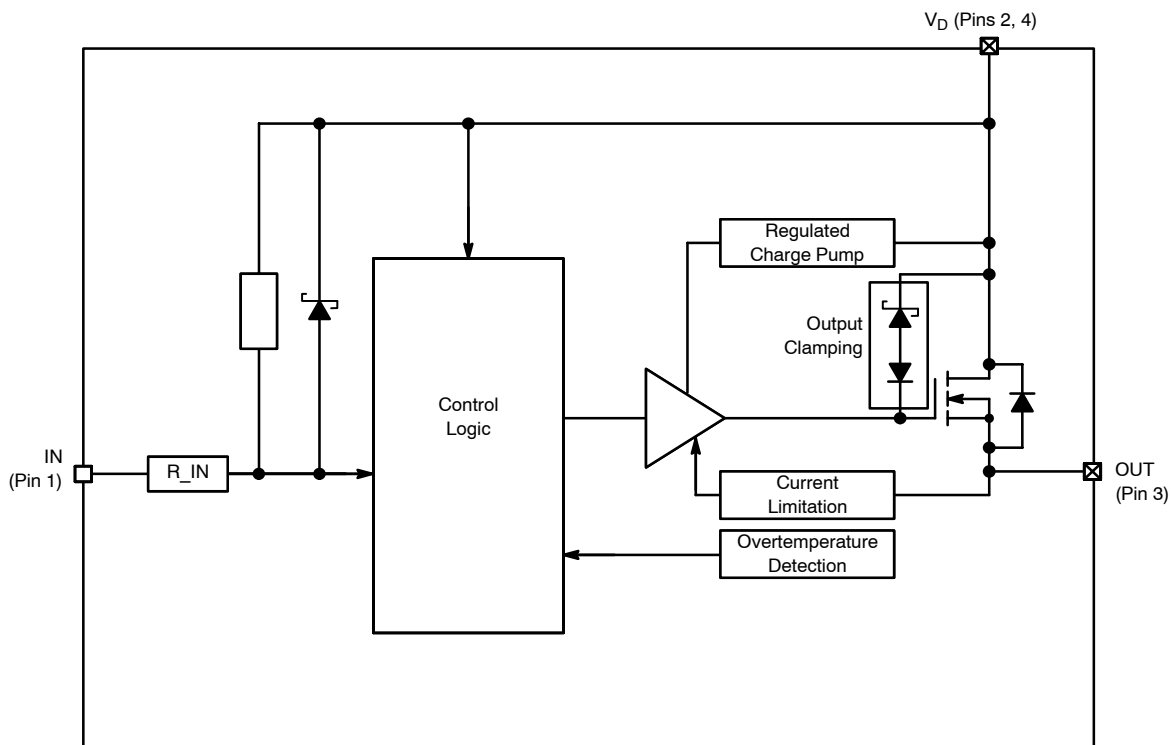


Figure 1. Block Diagram

PACKAGE PIN DESCRIPTION

Pin #	Symbol	Description
1	IN	Control Input, Active Low
2	V_D	Supply Voltage
3	OUT	Output
4	V_D	Supply Voltage

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MAXIMUM RATINGS

Rating	Symbol	Value		Unit
		Min	Max	
DC Supply Voltage (Note 1)	V_D	-16	45	V
Load Dump Protection ($R_I = 2 \Omega$, $t_d = 400 \text{ ms}$, $V_{IN} = 0, 10 \text{ V}$, $I_L = 150 \text{ mA}$, $V_{bb} = 13.5 \text{ V}$)	V_{Loaddump}		100	V
Input Current	I_{in}	-15	15	mA
Output Current (Note 1)	I_{out}		Internally Limited	A
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 2) @ $T_A = 25^\circ\text{C}$ (Note 3)	P_D		1.13 1.60	W
Electrostatic Discharge (Note 4) (Human Body Model (HBM) 100 pF/1500 Ω) Input All other			1 5	kV
Single Pulse Inductive Load Switching Energy (Note 4) ($V_{DD} = 13.5 \text{ V}$, $I = 465 \text{ mA}$, $L = 200 \text{ mH}$, $T_{J\text{Start}} = 150^\circ\text{C}$)	E_{AS}		29	mJ
Operating Junction Temperature	T_J	-40	+150	$^\circ\text{C}$
Storage Temperature	T_{storage}	-55	+150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Reverse Output current has to be limited by the load to stay within absolute maximum ratings and thermal performance.
- Minimum Pad.
- 1 in square pad size, FR-4, 1 oz Cu.
- Not subjected to production testing.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max Value	Unit
Thermal Resistance (Note 5) Junction-to-Ambient (Note 2) Junction-to-Ambient (Note 3)	$R_{\theta JA}$ $R_{\theta JA}$	110 78.3	K/W

- Not subjected to production testing.

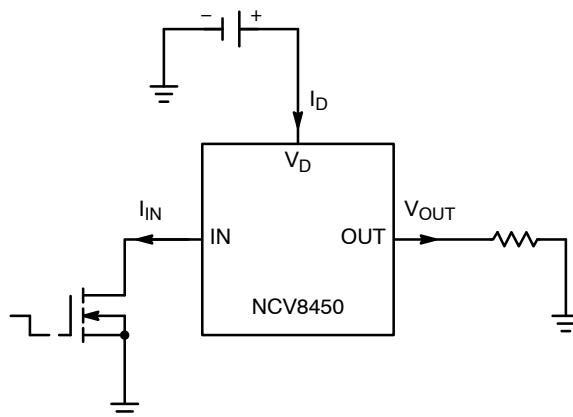


Figure 2. Applications Test Circuit

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ELECTRICAL CHARACTERISTICS (6 ≤ V_D ≤ 45 V; -40°C < T_J < 150°C unless otherwise specified)

Rating	Symbol	Conditions	Value			Unit
			Min	Typ	Max	

OUTPUT CHARACTERISTICS

Operating Supply Voltage	V _{SUPPLY}		4.5	-	45	V
On Resistance (Pin 1 Connected to GND)	R _{ON}	T _J = 25°C, I _{OUT} = 150 mA, V _D = 7 V - 45 V T _J = 150°C, I _{OUT} = 150 mA, V _D = 7 V - 45 V (Note 6) T _J = 25°C, I _{OUT} = 150 mA, V _D = 6 V		1.0 1.4	2 3	Ω
Standby Current (Pin 1 Open)	I _D	V _D ≤ 20 V V _D > 20 V		0.6	10 100	μA

INPUT CHARACTERISTICS

Input Current – Off State	I _{IN_OFF}	V _{OUT} ≤ 0.1 V, R _L = 270 Ω, T _J = 25°C V _{OUT} ≤ 0.1V, R _L = 270 Ω, T _J = 150°C (Note 6)	-50 -40			μA
Input Current – On State (Pin 1 Grounded)	I _{IN_ON}			1.5	3	mA
Input Resistance (Note 6)	R _{IN}			1		kΩ

SWITCHING CHARACTERISTICS

Turn-On Time (Note 7) (V _{IN} = V _D to 0 V) to 90% V _{OUT}	t _{ON}	R _L = 270 Ω (Note 6) V _D = 13.5 V, R _L = 270 Ω, T _J = 25°C		30	125 100	μs
Turn-Off Time (Note 7) (V _{IN} = 0 V to V _D) to 10% V _{OUT}	t _{OFF}	R _L = 270 Ω (Note 6) V _D = 13.5 V, R _L = 270 Ω, T _J = 25°C		60	175 150	μs
Slew Rate On (Note 7) (V _{IN} = V _D to 0V) 10% to 30% V _{OUT}	dV/dt _{ON}	R _L = 270 Ω (Note 6) V _D = 13.5 V, R _L = 270 Ω, T _J = 25°C		0.7	4 4	V/μs
Slew Rate Off (Note 7) (V _{IN} = 0 V to V _D) 70% to 40% V _{OUT}	dV/dt _{OFF}	R _L = 270 Ω (Note 6) V _D = 13.5 V, R _L = 270 Ω, T _J = 25°C		0.9	4 4	V/μs

OUTPUT DIODE CHARACTERISTICS (Note 6)

Drain-Source Diode Voltage	V _F	I _{OUT} = -0.2 A		0.6		V
Continuous Reverse Drain Current	I _S	T _J = 25°C			0.2	A

PROTECTION FUNCTIONS (Note 8)

Temperature Shutdown (Note 6)	T _{SD}		150	175	-	°C
Temperature Shutdown Hysteresis (Note 6)	T _{SD_HYST}			5		°C
Output Current Limit	I _{LIM}	T _J = -40°C, V _D = 13.5 V, t _m = 100 μs (Note 6) T _J = 25 °C, V _D = 13.5 V, t _m = 100 μs T _J = 150 °C, V _D = 13.5 V, t _m = 100 μs (Note 6)	0.5	0.8	1.5	A
Output Clamp Voltage (Inductive Load Switch Off) At V _{OUT} = V _D - V _{CLAMP}	V _{CLAMP}	I _{OUT} = 4 mA	45	52		V
Overvoltage Protection	V _{IN_CL}	I _{CLAMP} = 4 mA	50	54		V

6. Not subjected to production testing

7. Only valid with high input slew rates

8. Protection functions are not designed for continuous repetitive operation and are considered outside normal operating range

TYPICAL CHARACTERISTIC CURVES

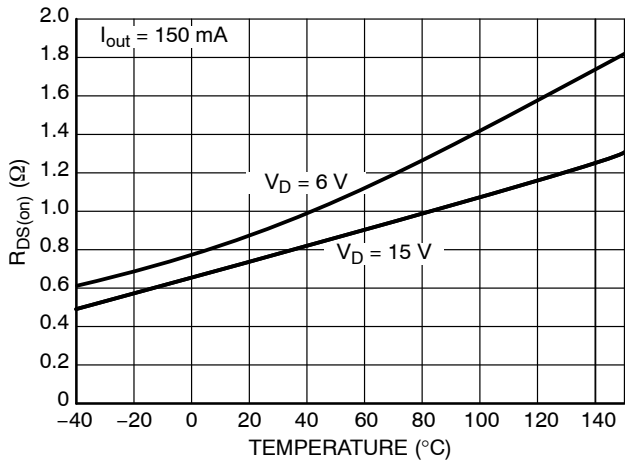


Figure 3. $R_{DS(on)}$ vs. Temperature

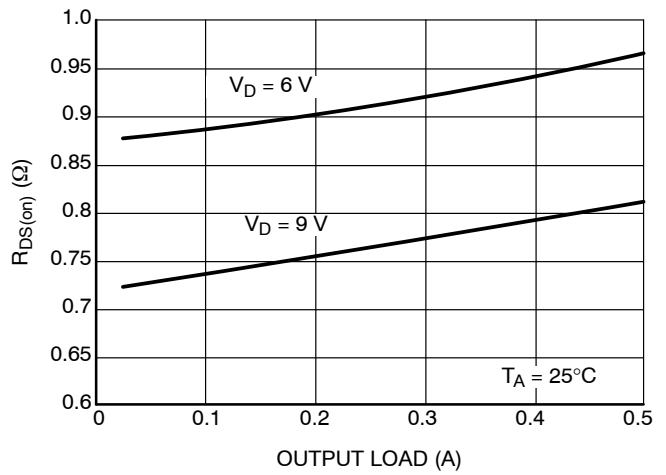


Figure 4. $R_{DS(on)}$ vs. Output Load

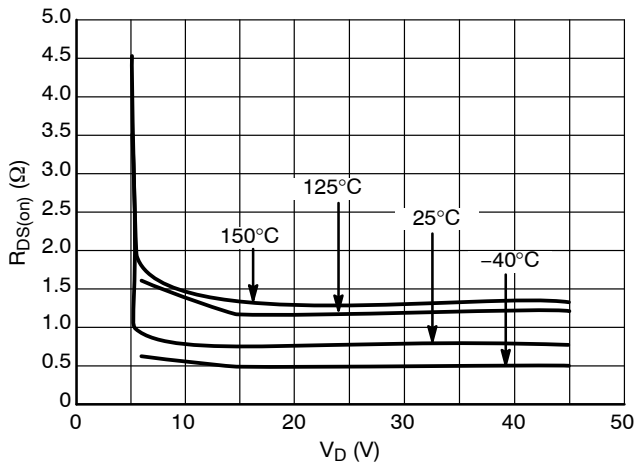


Figure 5. $R_{DS(on)}$ vs. V_D

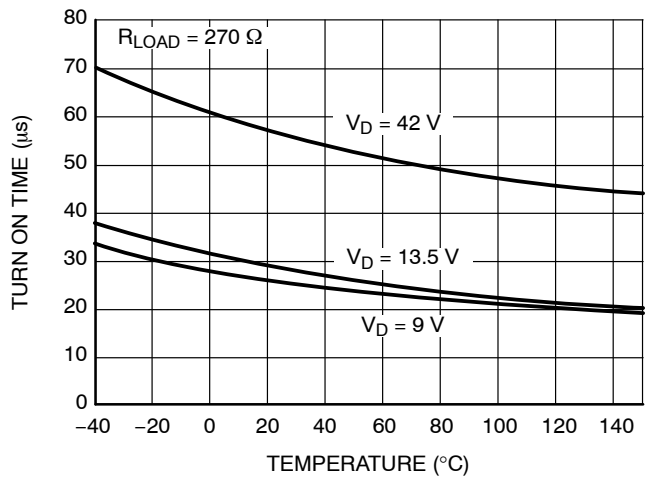


Figure 6. Turn On Time vs. Temperature

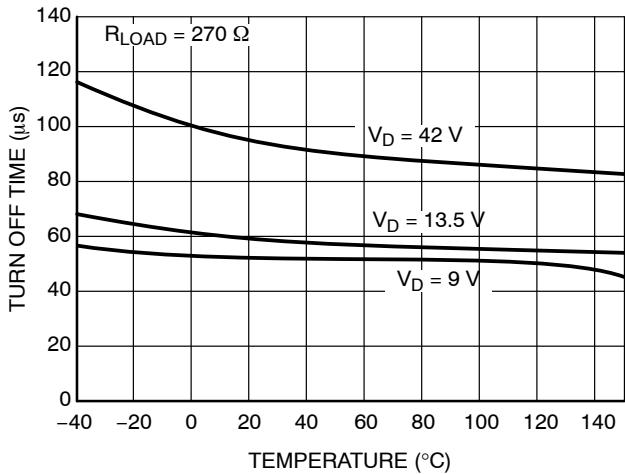


Figure 7. Turn Off Time vs. Temperature

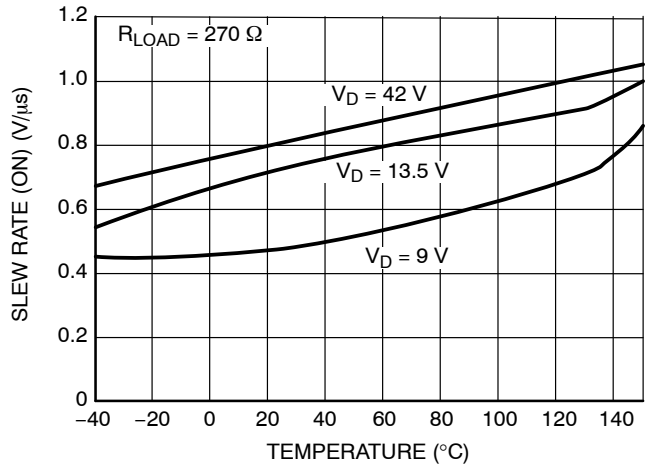


Figure 8. Slew Rate (ON) vs. Temperature

TYPICAL CHARACTERISTIC CURVES

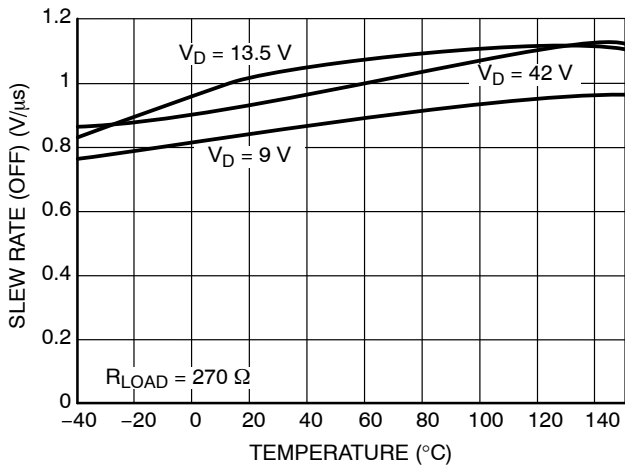


Figure 9. Slew Rate (OFF) vs. Temperature

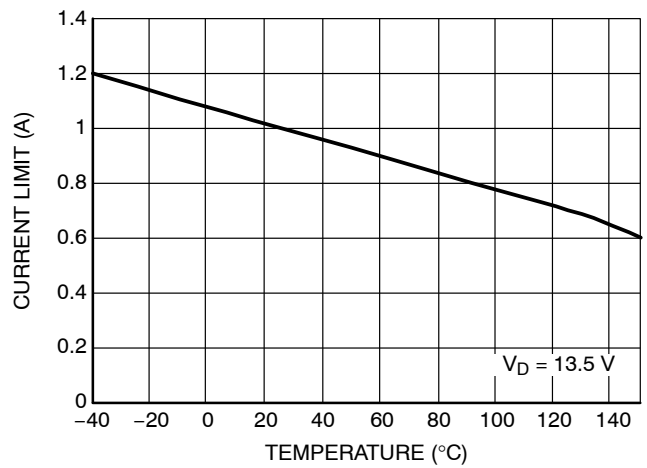


Figure 10. Current Limit vs. Temperature

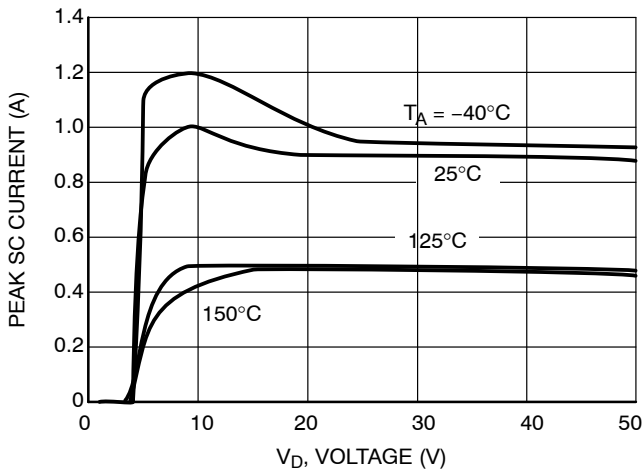


Figure 11. Peak Short Circuit Current vs. V_D Voltage

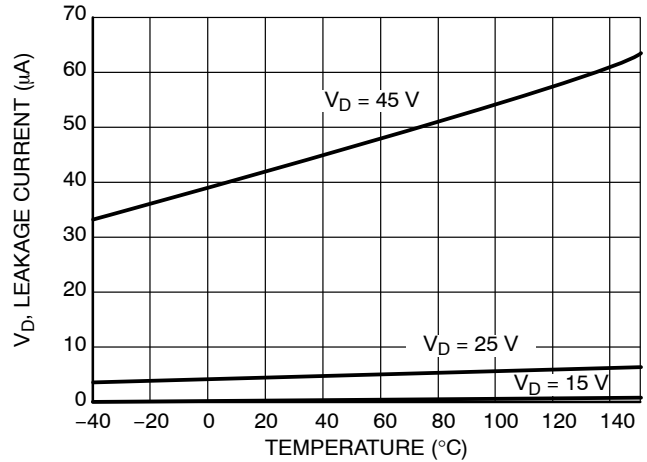


Figure 12. V_D Leakage Current vs. Temperature Off-State

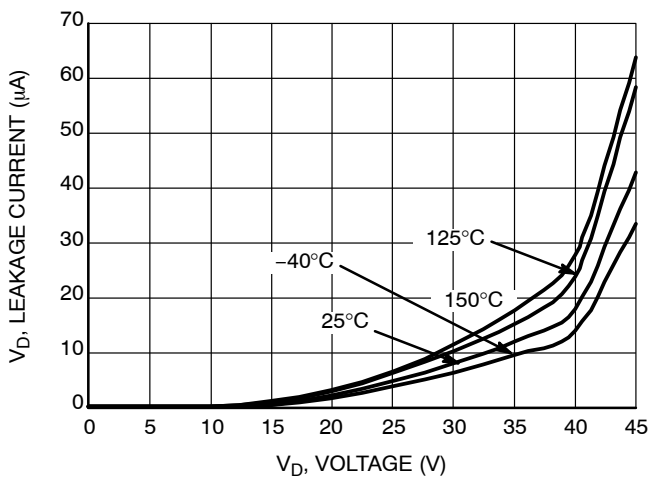


Figure 13. V_D Leakage Current vs. V_D Voltage Off-State

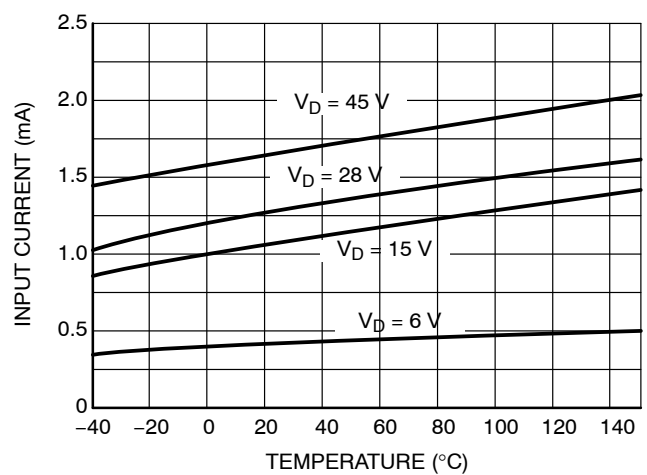


Figure 14. On-State Input Current vs. Temperature

TYPICAL CHARACTERISTIC CURVES

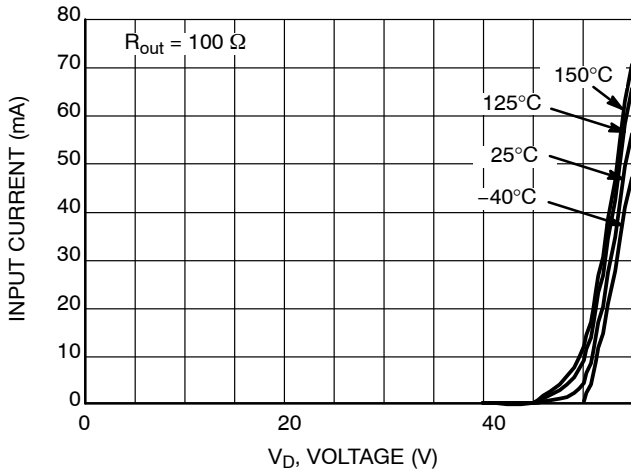


Figure 18. Input Current vs. V_D Voltage Off-State

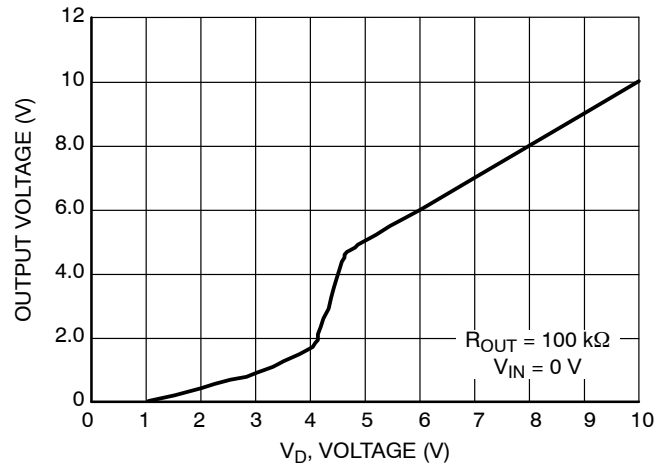


Figure 15. Output Voltage vs. V_D Voltage

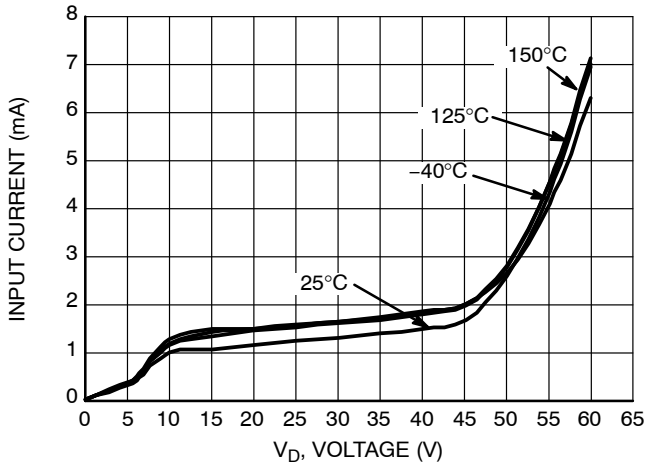


Figure 16. Input Current vs. V_D Voltage On-State

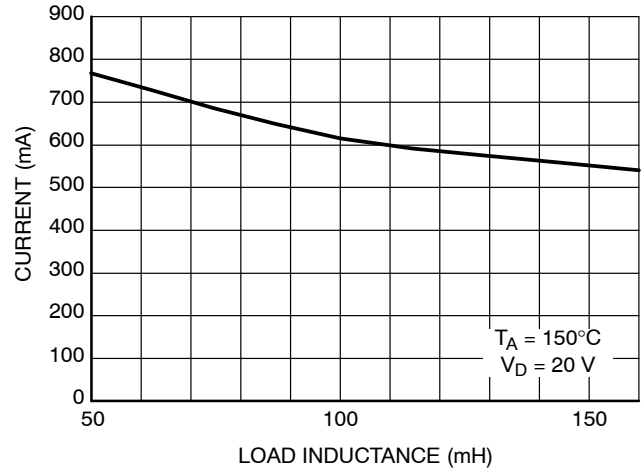


Figure 17. Single Pulse Maximum Switch-off Current vs. Load Inductance

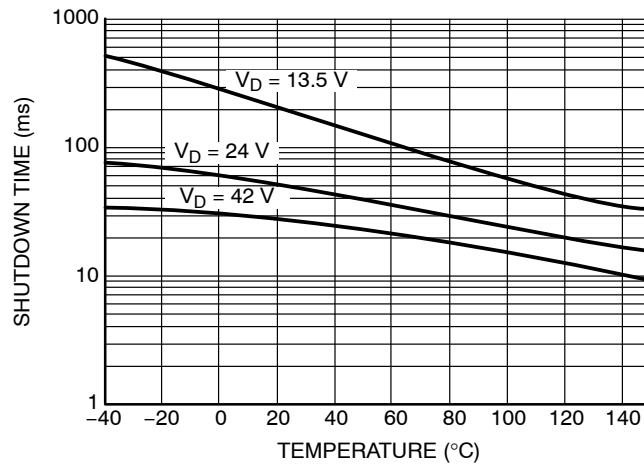


Figure 19. Initial Short-Circuit Shutdown Time vs. Temperature

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TYPICAL CHARACTERISTIC CURVES

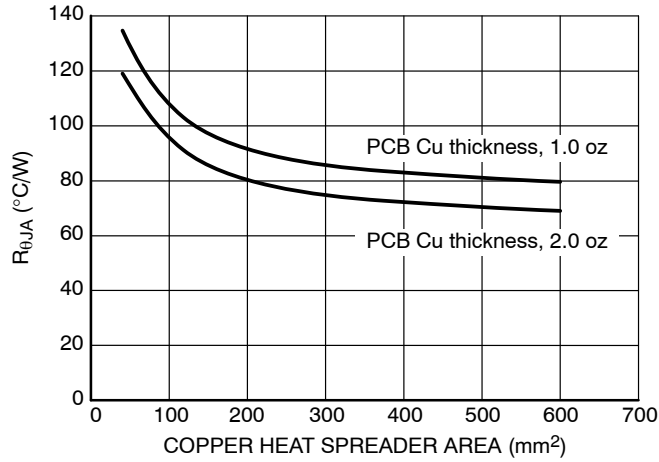


Figure 20. $R_{\theta JA}$ vs. Copper Area

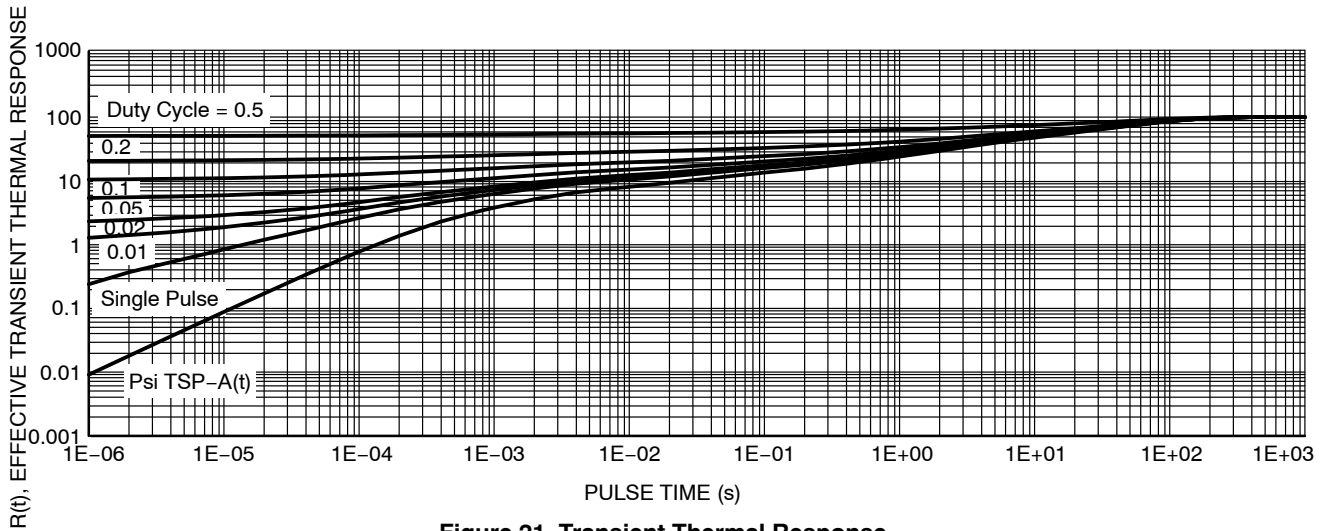


Figure 21. Transient Thermal Response

ISO PULSE TEST RESULTS

Test Pulse	Test Level	Test Results	Pulse Cycle Time and Generator Impedance
1	200 V	C	500 ms, 10 Ω
2	150 V	C	500 ms, 10 Ω
3a	200 V	C	100 ms, 50 Ω
3b	200 V	C	100 ms, 50 Ω
5	175 V	E(100 V)	400 ms, 2 Ω

ORDERING INFORMATION

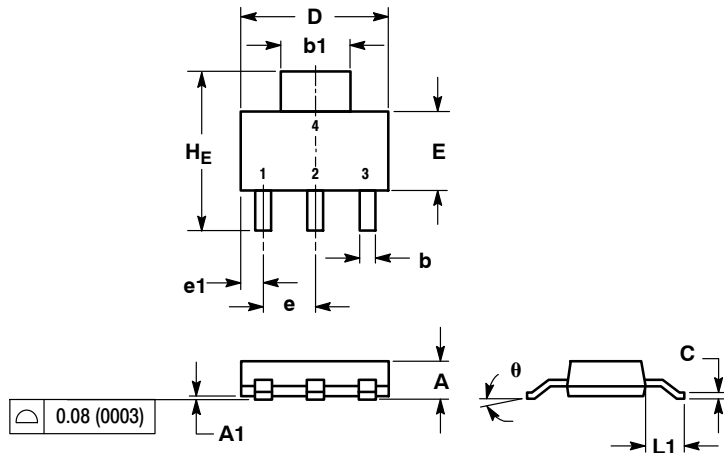
Device	Package	Shipping [†]
NCV8450STT3G	SOT-223 (Pb-Free)	4000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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PACKAGE DIMENSIONS

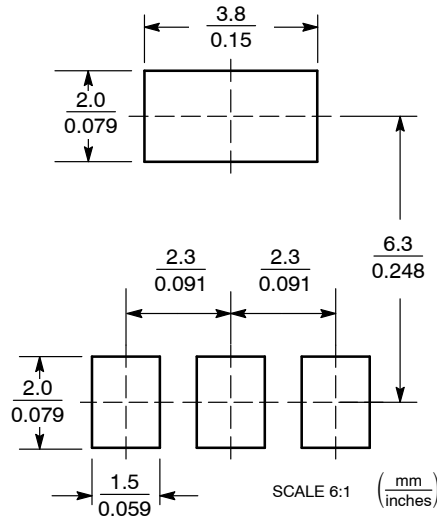
SOT-223 (TO-261)
CASE 318E-04
ISSUE M



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
c	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
e	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
H	1.50	1.75	2.00	0.060	0.069	0.078
L1	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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